

# RGEX5TS65DGC13

## 650V 75A Field Stop Trench IGBT

Datasheet

V <sub>CES</sub>	650V
I <sub>C</sub>	75A
V <sub>CE(sat) (Typ.)</sub>	1.65V
$P_{D}$	306W

# Outline TO-247GE

#### Features

- 1) Low Collector Emitter Saturation Voltage
- 2) Low Switching Loss
- 3) Short Circuit Withstand Time 5µs
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating; RoHS Compliant

#### Application

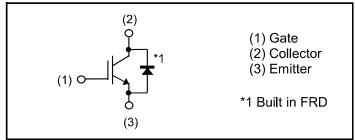
General Inverter

**UPS** 

**Power Conditioner** 

Welder

### ●Inner Circuit



Packaging Specifications

- r derkaging epocinications						
Type Packaging Reel Size (mm) Tape Width (mm) Basic Ordering Unit ( Packing Code Marking	Packaging	Tube				
	Reel Size (mm)	-				
	Tape Width (mm)	-				
	Basic Ordering Unit (pcs)	600				
	Packing Code	C13				
	Marking	RGEX5TS65D				

## ● **Absolute Maximum Ratings** (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		$V_{CES}$	650	V
Gate - Emitter Voltage		$V_{GES}$	±30	V
Collector Current	T <sub>C</sub> = 25°C	I <sub>C</sub>	102	Α
Collector Current	T <sub>C</sub> = 100°C	I <sub>C</sub>	75	А
Pulsed Collector Current		I <sub>CP</sub> *1	225	А
Diada Famuard Current	T <sub>C</sub> = 25°C	I <sub>F</sub>	92	А
Diode Forward Current	T <sub>C</sub> = 100°C	I <sub>F</sub>	54	Α
Diode Pulsed Forward Current		I <sub>FP</sub> *1	225	А
Dawar Dissination	T <sub>C</sub> = 25°C	P <sub>D</sub>	306	W
Power Dissipation	T <sub>C</sub> = 100°C	P <sub>D</sub>	153	W
Operating Junction Temperature		T <sub>j</sub>	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

<sup>\*1</sup> Pulse width limited by T<sub>imax.</sub>

## ●Thermal Resistance

Parameter	Symbol	Values			Unit
Farameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.49	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j-c)}$	1	1	0.74	°C/W

# ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
	Symbol		Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	ı	V
Collector Cut - off Current	I <sub>CES</sub>	$V_{CE} = 650V, V_{GE} = 0V$	ı	ı	10	μΑ
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V$ , $V_{CE} = 0V$	ı	ı	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 19.6mA$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_{C}$ = 75A, $V_{GE}$ = 15V, $T_{j}$ = 25°C $T_{j}$ = 175°C	- -	1.65 2.15	2.05 -	V

# ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Davamatas	Cura had	Conditions	Values			l locit
Parameter	Symbol		Min.	Тур.	Max.	Unit
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V,	-	4450	-	
Output Capacitance	C <sub>oes</sub>	$V_{GE} = 0V$ ,	-	194	-	рF
Reverse transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	48	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 400V,	-	162	-	
Gate - Emitter Charge	$Q_ge$	I <sub>C</sub> = 75A,	-	34	-	nC
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	66	-	
Turn - on Delay Time	t <sub>d(on)</sub>		-	69	-	
Rise Time	t <sub>r</sub>	$I_C = 75A, V_{CC} = 400V,$ $V_{GE} = 15V, R_G = 10\Omega,$	-	52	-	no
Turn - off Delay Time	t <sub>d(off)</sub>	$T_i = 25^{\circ}C$	-	210	-	ns
Fall Time	t <sub>f</sub>	Inductive Load *E <sub>on</sub> include diode reverse recovery	-	47	-	
Turn-on Switching Loss	E <sub>on</sub>		1	3.63	-	mJ
Turn-off Switching Loss	E <sub>off</sub>		-	1.74	-	
Turn - on Delay Time	t <sub>d(on)</sub>		I	69	-	
Rise Time	t <sub>r</sub>	$I_C = 75A, V_{CC} = 400V, V_{GE} = 15V, R_G = 10\Omega,$	-	55	-	ne
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 175°C Inductive Load	I	228	-	ns
Fall Time	t <sub>f</sub>		-	90	-	
Turn-on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	ı	3.79	-	mJ
Turn-off Switching Loss	E <sub>off</sub>		ī	2.18	-	1113
Reverse Bias Safe Operating Area	RBSOA	$I_C = 225A, V_{CC} = 520V,$ $V_p = 650V, V_{GE} = 15V,$ $R_G = 100\Omega, T_j = 175^{\circ}C$	FULL SQUARE		-	
Short Circuit Withstand Time	t <sub>sc</sub>	$V_{CC} \le 360V$ , $V_{GE} = 15V$ , $T_j = 25^{\circ}C$	5	-	-	μs

# **•FRD Electrical Characteristics** (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Cymbol	Conditions	Values			Unit
	Symbol		Min.	Тур.	Max.	Offic
		I <sub>F</sub> = 75A,				
Diode Forward Voltage	$V_{F}$	T <sub>j</sub> = 25°C	-	1.6	2.05	V
		T <sub>j</sub> = 175°C	-	1.65	-	
Diode Reverse Recovery Time	t <sub>rr</sub>		-	226	-	ns
Diode Peak Reverse Recovery Current	l <sub>rr</sub>	$I_{F} = 75A,$ $V_{CC} = 400V,$	-	16.2	-	А
Diode Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>⊧</sub> /dt = 500A/µs, T <sub>j</sub> = 25°C	-	1.8	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	283	-	μJ
Diode Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 75A, V <sub>CC</sub> = 400V,	-	240	ı	ns
Diode Peak Reverse Recovery Current	l <sub>rr</sub>		-	22.8	-	А
Diode Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt = 500A/µs, T <sub>j</sub> = 175°C	_	3.2	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	581	-	μJ

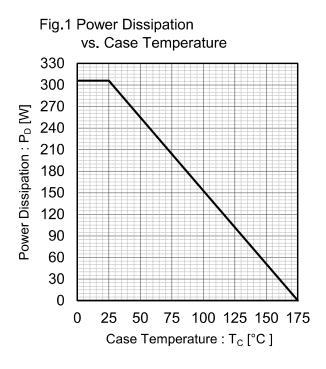
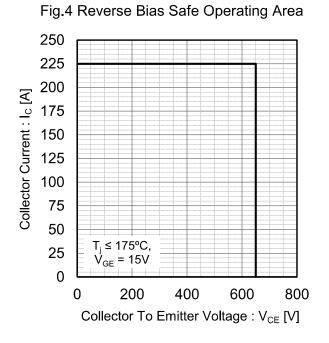


Fig.2 Collector Current vs. Case Temperature 120 100 Collector Current : Ic [A] 80 60 40 20 V<sub>GE</sub> ≥ 15V 0 50 75 100 125 150 175 0 25 Case Temperature : T<sub>C</sub> [°C]

Fig.3 Forward Bias Safe Operating Area 1000 10µs 100 Collector Current : Ic [A] 100µs 10 1 0.1  $T_{\rm C} = 25^{\circ}{\rm C}$ Single Pulse 0.01 10 100 1000 Collector To Emitter Voltage: V<sub>CE</sub> [V]



Collector To Emitter Saturation

Voltage: V<sub>CE(sat)</sub> [V]

Fig.5 Typical Output Characteristics

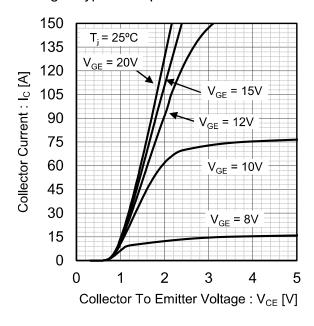


Fig.6 Typical Output Characteristics

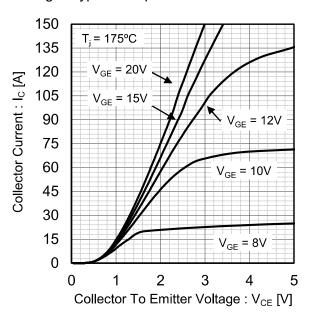


Fig.7 Typical Transfer Characteristics

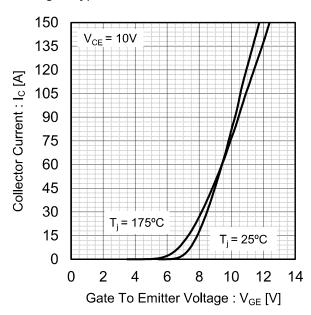
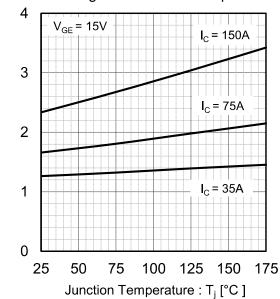


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



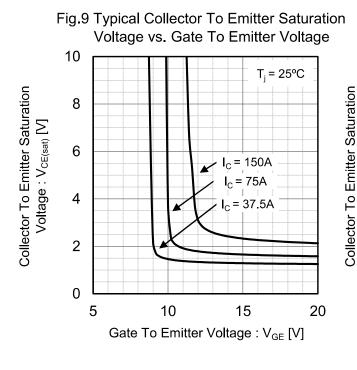
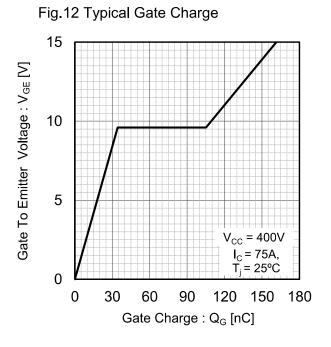
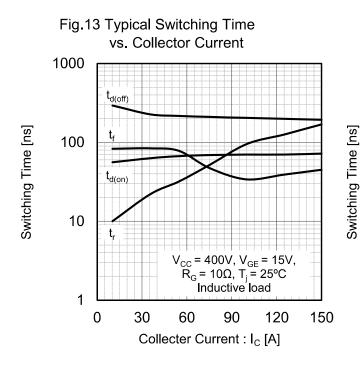


Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage 10 T<sub>i</sub> = 175°C 8 Voltage: V<sub>CE(sat)</sub> [V]  $I_{c} = 150A$ 6 = 75A = 37.5A 4 2 0 5 10 15 20 Gate To Emitter Voltage :  $V_{GE}[V]$ 

Fig.11 Typical Capacitance vs. Collector To Emitter Voltage 100000  $\mathsf{C}_{\mathsf{ies}}$ 10000 Capacitance [pF] 1000 C<sub>oes</sub> 100 10  $\mathsf{C}_{\mathsf{res}}$ f = 1MHz $V_{GE} = 0V$ = 25°C 0.01 1 10 100 0.1 Collector To Emitter Voltage: V<sub>CE</sub> [V]





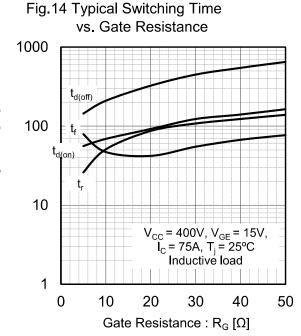
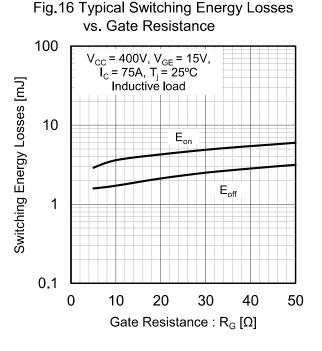
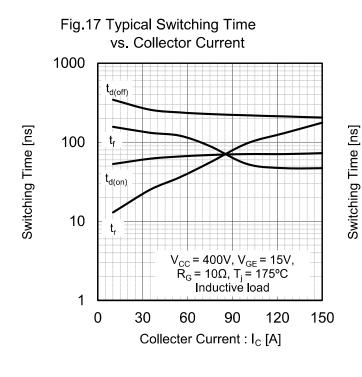


Fig.15 Typical Switching Energy Losses vs. Collector Current 100  $V_{CC} = 400V, V_{GE} = 15V,$   $R_G = 10\Omega, T_j = 25^{\circ}C$ Switching Energy Losses [mJ] Inductive load 10  $\mathsf{E}_{\mathsf{on}}$  $\mathsf{E}_{\mathsf{off}}$ 1 0.1 60 30 90 120 150 0 Collecter Current : I<sub>C</sub> [A]





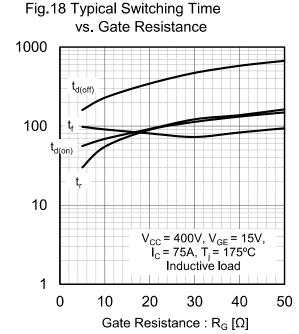
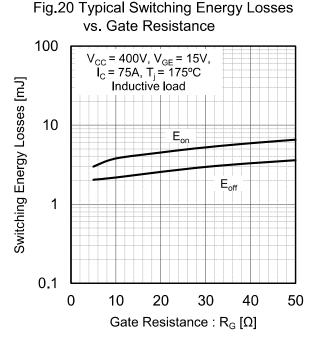


Fig.19 Typical Switching Energy Losses vs. Collector Current 100  $V_{CC} = 400V, V_{GE} = 15V,$   $R_{G} = 10\Omega, T_{j} = 175^{\circ}C$ Switching Energy Losses [mJ] Inductivé load 10  $\mathsf{E}_{\mathsf{on}}$ 1 0.1 30 60 90 120 150 0 Collecter Current : I<sub>C</sub> [A]



#### ● Electrical Characteristic Curves

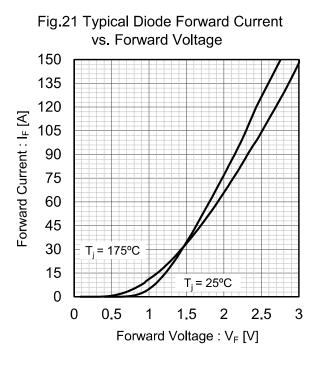
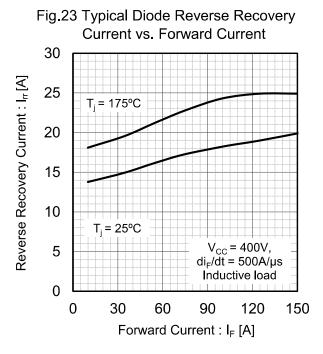


Fig.22 Typical Diode Reverce Recovery Time vs. Forward Current 400 Reverse Recovery Time : t<sub>rr</sub> [ns] 300 T<sub>i</sub> = 175°C 200 100 T<sub>i</sub> = 25°C  $V_{CC} = 400V$ ,  $di_F/dt = 500A/\mu s$ Inductive load 0 0 30 60 90 120 150 Forward Current : I<sub>F</sub> [A]



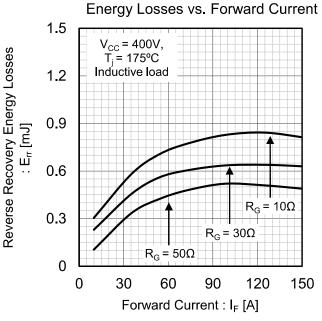


Fig.24 Typical Diode Reverse Recovery



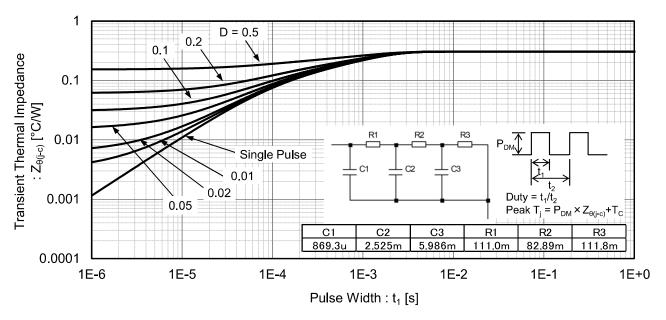
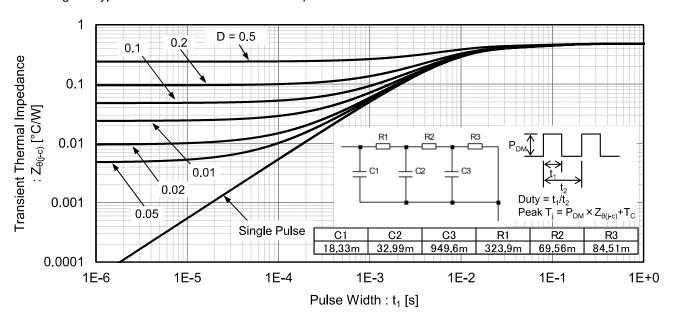


Fig.26 Typical Diode Transient Thermal Impedance



## ●Inductive Load Switching Circuit and Waveform and Short Circuit

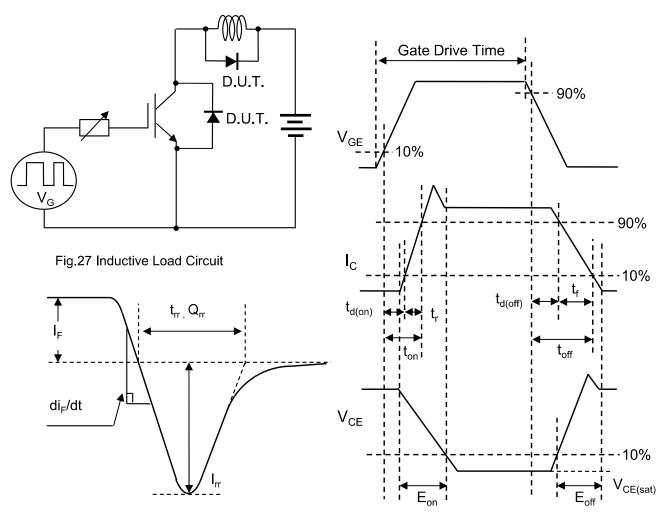


Fig.28 Diode Reverse Recovery Waveform

Fig.29 Inductive Load Waveform

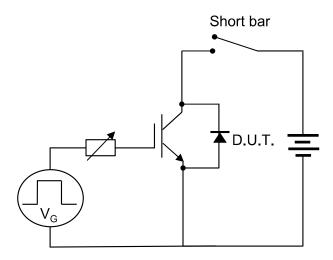


Fig.30 Short Circuit

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